THE DATASHEET OF

CY7C025-25AXC

CY7C024/024A/0241
CY7C025/0251

4K x 16/18 and 8K x 16/18 Dual-Port Static RAM with SEM, INT, BUSY

Features

- True dual-ported memory cells, which allow simultaneous reads of the same memory location
- 4K x 16 organization (CY7C024/024A[1])
- 4K x 18 organization (CY7C0241)
- 8K x 16 organization (CY7C025)
- 8K x 18 organization (CY7C0251)
- 0.65 micron CMOS for optimum speed and power
- High speed access: 15 ns
- Low operating power: I_{CC} = 150 mA (typ)
- Fully asynchronous operation
- Automatic power down
- Expandable data bus to 32/36 bits or more using Master/Slave chip select when using more than one device
- On-chip arbitration logic
- Semaphores included to permit software handshaking between ports
- $\overline{INT}$ flag for port-to-port communication
- Separate upper-byte and lower-byte control
- Pin select for Master or Slave
- Available in 84-pin (Pb-free) PLCC, 84-pin PLCC, 100-pin (Pb-free) TQFP, and 100-pin TQFP

Functional Description

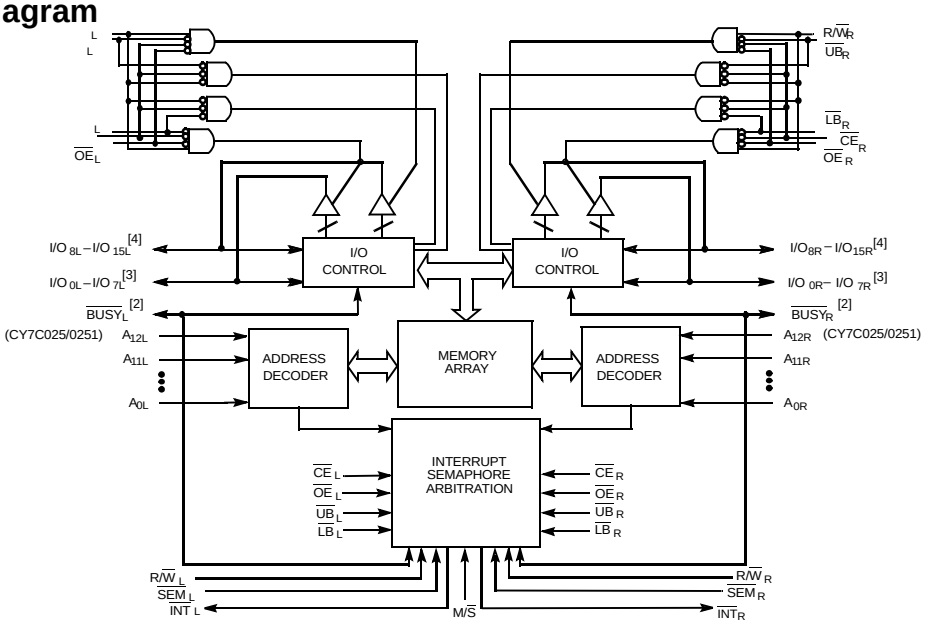
The CY7C024/024A/0241 and CY7C025/0251 are low power CMOS 4K x 16/18 and 8K x 16/18 dual-port static RAMs. Various arbitration schemes are included on the CY7C024/ 0241 and CY7C025/0251 to handle situations when multiple processors access the same piece of data. Two ports are provided, permitting independent, asynchronous access for reads and writes to any location in memory. The CY7C024/ 0241 and CY7C025/0251 can be used as standalone 16 or 18-bit dual-port static RAMs or multiple devices can be combined to function as a 32-/36-bit or wider master/ slave dual-port static RAM. An M/$\overline{S}$ pin is provided for implementing 32-/36-bit or wider memory applications without the need for separate master and slave devices or additional discrete logic. Application areas include interprocessor/multiprocessor designs, communications status buffering, and dual-port video/graphics memory.

Each port has independent control pins: Chip Enable ($\overline{CE}$), Read or Write Enable (R/$\overline{W}$), and Output Enable ($\overline{OE}$). Two flags are provided on each port ($\overline{BUSY}$ and $\overline{INT}$). $\overline{BUSY}$ signals that the port is trying to access the same location currently being accessed by the other port. The Interrupt Flag ($\overline{INT}$) permits communication between ports or systems by means of a mail box. The semaphores are used to pass a flag, or token, from one port to the other to indicate that a shared resource is in use. The semaphore logic is comprised of eight shared latches. Only one side can control the latch (semaphore) at any time. Control of a semaphore indicates that a shared resource is in use. An automatic power down feature is controlled independently on each port by a chip select ($\overline{CE}$) pin.

The CY7C024/024A/0241 and CY7C025/0251 are available in 84-pin Pb-free PLCCs, 84-pin PLCCs (CY7C024 and CY7C025 only), 100-pin Pb-free Thin Quad Plastic Flatplack (TQFP), and 100-pin Thin Quad Plastic Flatpack.

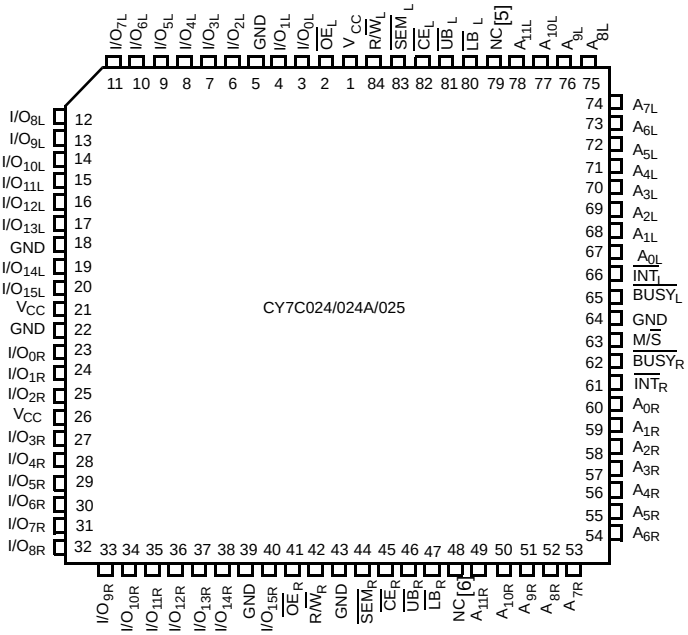
Note
1. CY7C024 and CY7C024A are functionally identical.

Logic Block Diagram



Pin Configurations

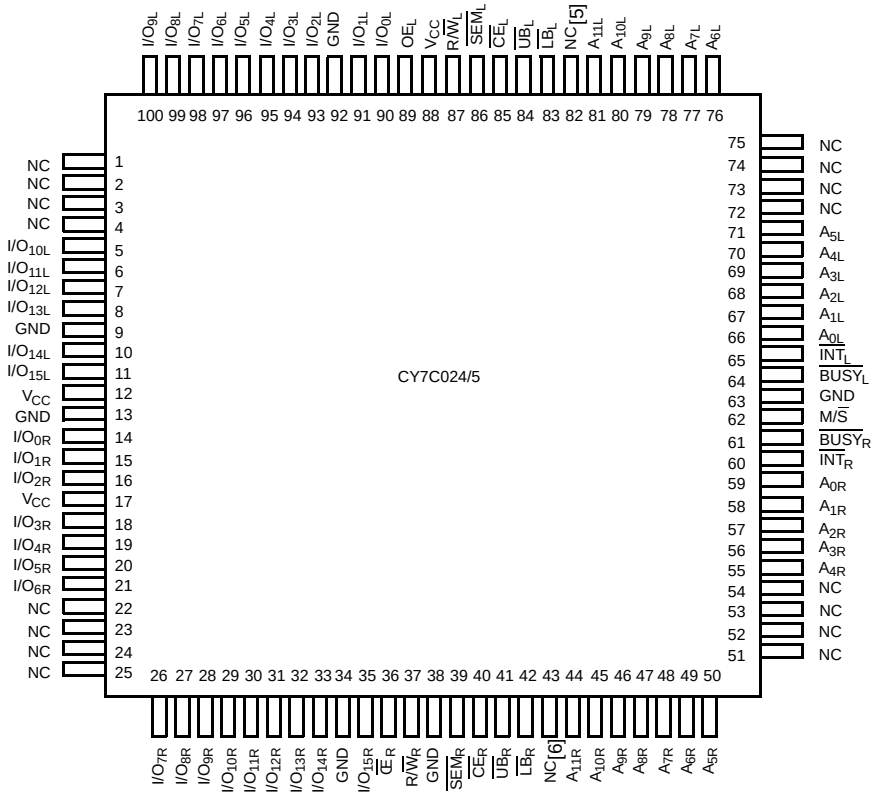
Figure 1. 84-Pin PLCC (Top View)



Notes
2. $\overline{BUSY}$ is an output in master mode and an input in slave mode.
3. I/O_0 –I/O_8 on the CY7C0241/0251.
4. I/O_9 –I/O_{17} on the CY7C0241/0251.
5. A_{12L} on the CY7C025/0251.
6. A_{12R} on the CY7C025/0251.

Pin Configurations (continued)

Figure 2. 100-Pin TQFP (Top View)



Pin Definitions

Left Port	Right Port	Description
$\overline{CE}_L$	$\overline{CE}_R$	Chip Enable
$R/\overline{W}_L$	$R/\overline{W}_R$	Read/Write Enable
$\overline{OE}_L$	$\overline{OE}_R$	Output Enable
A_{0L}–$A_{11/12L}$	A_{0R}–$A_{11/12R}$	Address
I/O_{0L}–$I/O_{15/17L}$	I/O_{0R}–$I/O_{15/17R}$	Data Bus Input/Output
$\overline{SEM}_L$	$\overline{SEM}_R$	Semaphore Enable
$\overline{UB}_L$	$\overline{UB}_R$	Upper Byte Select
$\overline{LB}_L$	$\overline{LB}_R$	Lower Byte Select
$\overline{INT}_L$	$\overline{INT}_R$	Interrupt Flag
$\overline{BUSY}_L$	$\overline{BUSY}_R$	Busy Flag
$M/\overline{S}$		Master or Slave Select
V_{CC}		Power
GND		Ground

Selection Guide

Parameter	7C024/024A/0241–15 7C025/0251–15	7C024/0241–25 7C025/0251–25	7C024/0241–35 7C025/0251–35	7C024/0241–55 7C025/0251–55
Maximum Access Time (ns)	15	25	35	55
Typical Operating Current (mA)	190	170	160	150
Typical Standby Current for I_{SB1} (mA)	50	40	30	20

Architecture

The CY7C024/024A/0241 and CY7C025/0251 consist of an array of 4K words of 16/18 bits each and 8K words of 16/18 bits each of dual-port RAM cells, I/O and address lines, and control signals (CE, OE, R/W). These control pins permit independent access for reads or writes to any location in memory. To handle simultaneous writes/reads to the same location, a BUSY pin is provided on each port. Two interrupt (INT) pins can be used for port-to-port communication. Two semaphore (SEM) control pins are used for allocating shared resources. With the M/S pin, the CY7C024/024A/0241 and CY7C025/0251 can function as a master (BUSY pins are outputs) or as a slave (BUSY pins are inputs). The CY7C024/024A/0241 and CY7C025/0251 have an automatic power down feature controlled by CE. Each port is provided with its own output enable control (OE), which allows data to be read from the device.

Functional Description

Write Operation

Data must be set up for a duration of t_{SD} before the rising edge of R/W to guarantee a valid write. A write operation is controlled by either the R/W pin (see Figure 7) or the CE pin (see Figure 8). Required inputs for non contention operations are summarized in Table 1.

If a location is being written to by one port and the opposite port attempts to read that location, a port-to-port flowthrough delay must occur before the data is read on the output; otherwise the data read is not deterministic. Data is valid on the port t_{DDD} after the data is presented on the other port.

Read Operation

When reading the device, the user must assert both the OE and CE pins. Data is available t_{ACE} after CE or t_{DOE} after OE is asserted. If the user of the CY7C024/024A/0241 or CY7C025/0251 wishes to access a semaphore flag, then the SEM pin must be asserted instead of the CE pin, and OE must also be asserted.

Interrupts

The upper two memory locations may be used for message passing. The highest memory location (FFF for the CY7C024/024A/0241, 1FFF for the CY7C025/0251) is the mailbox for the right port and the second-highest memory location (FFE for the CY7C024/024A/0241, 1FFE for the CY7C025/0251) is the mailbox for the left port. When one port writes to the other port's mailbox, an interrupt is generated to the owner. The interrupt is reset when the owner reads the contents of the mailbox. The message is user defined.

Each port can read the other port's mailbox without resetting the interrupt. The active state of the BUSY signal (to a port) prevents the port from setting the interrupt to the winning port. Also, an active BUSY to a port prevents that port from reading its own mailbox and thus resetting the interrupt to it.

If your application does not require message passing, do not connect the interrupt pin to the processor's interrupt request input pin.

The operation of the interrupts and their interaction with Busy are summarized in *Table 2* on page 5.

Busy

The CY7C024/024A/0241 and CY7C025/0251 provide on-chip arbitration to resolve simultaneous memory location access (contention). If both ports' CEs are asserted and an address match occurs within t_{PS} of each other, the busy logic determines which port has access. If t_{PS} is violated, one port definitely gains permission to the location, but which one is not predictable. BUSY is asserted t_{BLA} after an address match or t_{BLC} after CE is taken LOW.

Master/Slave

A M/S pin is provided to expand the word width by configuring the device as either a master or a slave. The BUSY output of the master is connected to the BUSY input of the slave. This allows the device to interface to a master device with no external components. Writing to slave devices must be delayed until after the BUSY input has settled (t_{BLC} or t_{BLA}). Otherwise, the slave chip may begin a write cycle during a contention situation. When tied HIGH, the M/S pin allows the device to be used as a master and, therefore, the BUSY line is an output. BUSY can then be used to send the arbitration outcome to a slave.

Semaphore Operation

The CY7C024/024A/0241 and CY7C025/0251 provide eight semaphore latches, which are separate from the dual-port memory locations. Semaphores are used to reserve resources that are shared between the two ports. The state of the semaphore indicates that a resource is in use. For example, if the left port wants to request a given resource, it sets a latch by writing a zero to a semaphore location. The left port then verifies its success in setting the latch by reading it. After writing to the semaphore, SEM or OE must be deasserted for tSOP before attempting to read the semaphore. The semaphore value is available $t_{SWRD} + t_{DOE}$ after the rising edge of the semaphore write. If the left port was successful (reads a zero), it assumes control of the shared resource, otherwise (reads a one) it assumes the right port has control and continues to poll the semaphore. When the right side has relinquished control of the semaphore (by writing a one), the left side succeeds in gaining control of the semaphore. If the left side no longer requires the semaphore, a one is written to cancel its request.

Semaphores are accessed by asserting $\overline{SEM}$ LOW. The $\overline{SEM}$ pin functions as a chip select for the semaphore latches ($\overline{CE}$ must remain HIGH during $\overline{SEM}$ LOW). A0–2 represents the semaphore address. $\overline{OE}$ and R/$\overline{W}$ are used in the same manner as a normal memory access. When writing or reading a semaphore, the other address pins have no effect.

When writing to the semaphore, only I/O_0 is used. If a zero is written to the left port of an available semaphore, a one appears at the same semaphore address on the right port. That semaphore can now only be modified by the side showing zero (the left port in this case). If the left port now relinquishes control by writing a one to the semaphore, the semaphore is set to one for both sides. However, if the right port had requested the semaphore (written a zero) while the left port had control, the right port immediately owns the semaphore as soon as the left port released it. Table 3 shows sample semaphore operations.

When reading a semaphore, all sixteen/eighteen data lines output the semaphore value. The read value is latched in an output register to prevent the semaphore from changing state during a write from the other port. If both ports attempt to access the semaphore within t_{SPS} of each other, the semaphore is definitely obtained by one side or the other, but there is no guarantee which side controls the semaphore

Table 1. Non-Contending Read/Write

Inputs						Outputs		Operation
$\overline{CE}$	R/$\overline{W}$	$\overline{OE}$	$\overline{UB}$	$\overline{LB}$	$\overline{SEM}$	I/O_0–I/O_7[3]	I/O_8–I/O_{15}[4]	
H	X	X	X	X	H	High Z	High Z	Deselected: Power Down
X	X	X	H	H	H	High Z	High Z	Deselected: Power Down
L	L	X	L	H	H	High Z	Data In	Write to Upper Byte Only
L	L	X	H	L	H	Data In	High Z	Write to Lower Byte Only
L	L	X	L	L	H	Data In	Data In	Write to Both Bytes
L	H	L	L	H	H	High Z	Data Out	Read Upper Byte Only
L	H	L	H	L	H	Data Out	High Z	Read Lower Byte Only
L	H	L	L	L	H	Data Out	Data Out	Read Both Bytes
X	X	H	X	X	X	High Z	High Z	Outputs Disabled
H	H	L	X	X	L	Data Out	Data Out	Read Data in Semaphore Flag
X	H	L	H	H	L	Data Out	Data Out	Read Data in Semaphore Flag
H	⎍	X	X	X	L	Data In	Data In	Write D_{IN0} into Semaphore Flag
X	⎍	X	H	H	L	Data In	Data In	Write D_{IN0} into Semaphore Flag
L	X	X	L	X	L			Not Allowed
L	X	X	X	L	L			Not Allowed

Table 2. Interrupt Operation Example (Assumes $\overline{BUSY}_L$=$\overline{BUSY}_R$=HIGH)[7]

Function	Left Port					Right Port				
	R/$\overline{W}_L$	$\overline{CE}_L$	$\overline{OE}_L$	$A_{0L–11L}$	$\overline{INT}_L$	R/$\overline{W}_R$	$\overline{CE}_R$	$\overline{OE}_R$	$A_{0R–11R}$	$\overline{INT}_R$
Set Right $\overline{INT}_R$ Flag	L	L	X	(1)FFF	X	X	X	X	X	L[9]
Reset Right $\overline{INT}_R$ Flag	X	X	X	X	X	X	L	L	(1)FFF	H[8]
Set Left $\overline{INT}_L$ Flag	X	X	X	X	L[8]	L	L	X	(1)FFE	X
Reset Left $\overline{INT}_L$ Flag	X	L	L	(1)FFE	H[9]	X	X	X	X	X

Table 3. Semaphore Operation Example

Function	I/O_0–$I/O_{15/17}$ Left	I/O_0–$I/O_{15/17}$ Right	Status
No action	1	1	Semaphore-free
Left port writes 0 to semaphore	0	1	Left Port has semaphore token
Right port writes 0 to semaphore	0	1	No change. Right side has no write access to semaphore.
Left port writes 1 to semaphore	1	0	Right port obtains semaphore token
Left port writes 0 to semaphore	1	0	No change. Left port has no write access to semaphore
Right port writes 1 to semaphore	0	1	Left port obtains semaphore token
Left port writes 1 to semaphore	1	1	Semaphore-free
Right port writes 0 to semaphore	1	0	Right port has semaphore token
Right port writes 1 to semaphore	1	1	Semaphore-free
Left port writes 0 to semaphore	0	1	Left port has semaphore token
Left port writes 1 to semaphore	1	1	Semaphore-free

Notes
7. A_{0L-12L} and A_{0R-12R}, 1FFF/1FFE for the CY7C025.
8. If $\overline{BUSY}_R$=L, then no change.
9. If $\overline{BUSY}_L$=L, then no change.

Maximum Ratings [10]

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Storage Temperature ..... –65°C to +150°C

Ambient Temperature with Power Applied ..... –55°C to +125°C

Supply Voltage to Ground Potential.....–0.3V to +7.0V

DC Voltage Applied to Outputs in High-Z State.....–0.5V to +7.0V

DC Input Voltage[11].....–0.5V to +7.0V

Output Current into Outputs (LOW)..... 20 mA

Static Discharge Voltage..... > 2001V (per MIL-STD-883, Method 3015)

Latch Up Current ..... > 200 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0°C to +70°C	5V ± 10%
Industrial	–40°C to +85°C	5V ± 10%

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions		7C024/024A/0241–15 7C025/0251–15			7C024/024A/0241–25 7C025/0251–25			Unit
				Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output HIGH Voltage	V_{CC} = Min, I_{OH} = –4.0 mA		2.4			2.4			V
V_{OL}	Output LOW Voltage	V_{CC} = Min, I_{OL} = 4.0 mA				0.4			0.4	V
V_{IH}	Input HIGH Voltage			2.2			2.2			V
V_{IL}	Input LOW Voltage			–0.7		0.8	–0.7		0.8	V
I_{IX}	Input Leakage Current	GND ≤ V_I ≤ V_{CC}		–10		+10	–10		+10	µA
I_{OZ}	Output Leakage Current	Output Disabled, GND ≤ V_O ≤ V_{CC}		–10		+10	–10		+10	µA
I_{CC}	Operating Current	V_{CC} = Max, I_{OUT} = 0 mA, Outputs Disabled	Com'l		190	300		170	250	mA
			Ind		200	320		170	290	
I_{SB1}	Standby Current (Both Ports TTL Levels)	$\overline{CE}_L$ and $\overline{CE}_R$ ≥ V_{IH}, f = f_{MAX}[12]	Com'l		50	70		40	60	mA
			Ind		50	70			75	
I_{SB2}	Standby Current (One Port TTL Level)	$\overline{CE}_L$ or $\overline{CE}_R$ ≥ V_{IH}, f = f_{MAX}[12]	Com'l		120	180		100	150	mA
			Ind		120	180		100	170	
I_{SB3}	Standby Current (Both Ports CMOS Levels)	Both Ports $\overline{CE}$ and $\overline{CE}_R$ ≥ V_{CC} – 0.2V, V_{IN} ≥ V_{CC} – 0.2V or V_{IN} ≤ 0.2V, f = 0[12]	Com'l		3	15		3	15	mA
			Ind		3	15		3	15	
I_{SB4}	Standby Current (Both Ports CMOS Levels)	One Port $\overline{CE}_L$ or $\overline{CE}_R$ ≥ V_{CC} – 0.2V, V_{IN} ≥ V_{CC} – 0.2V or V_{IN} ≤ 0.2V, Active Port Outputs, f = f_{MAX}[12]	Com'l		110	160		90	130	mA
			Ind		110	160		90	150	

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions	7C024/024A/0241–35 7C025/0251–35			7C024/024A/0241–55 7C025/0251–55			Unit
			Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output HIGH Voltage	V_{CC} = Min, I_{OH} = –4.0 mA	2.4			2.4			V
V_{OL}	Output LOW Voltage	V_{CC} = Min, I_{OL} = 4.0 mA			0.4			0.4	V
V_{IH}	Input HIGH Voltage		2.2			2.2			V
V_{IL}	Input LOW Voltage		–0.7		0.8	–0.7		0.8	V
I_{IX}	Input Leakage Current	GND ≤ V_I ≤ V_{CC}	–10		+10	–10		+10	µA
I_{OZ}	Output Leakage Current	Output Disabled, GND ≤ V_O ≤ V_{CC}	–10		+10	–10		+10	µA

Notes
10. The voltage on any input or I/O pin cannot exceed the power pin during power up
11. Pulse width < 20 ns.
12. $f_{MAX} = 1/t_{RC}$ = All inputs cycling at f = $1/t_{RC}$ (except output enable). f = 0 means no address or control lines change. This applies only to inputs at CMOS level standby I_{SB3}.

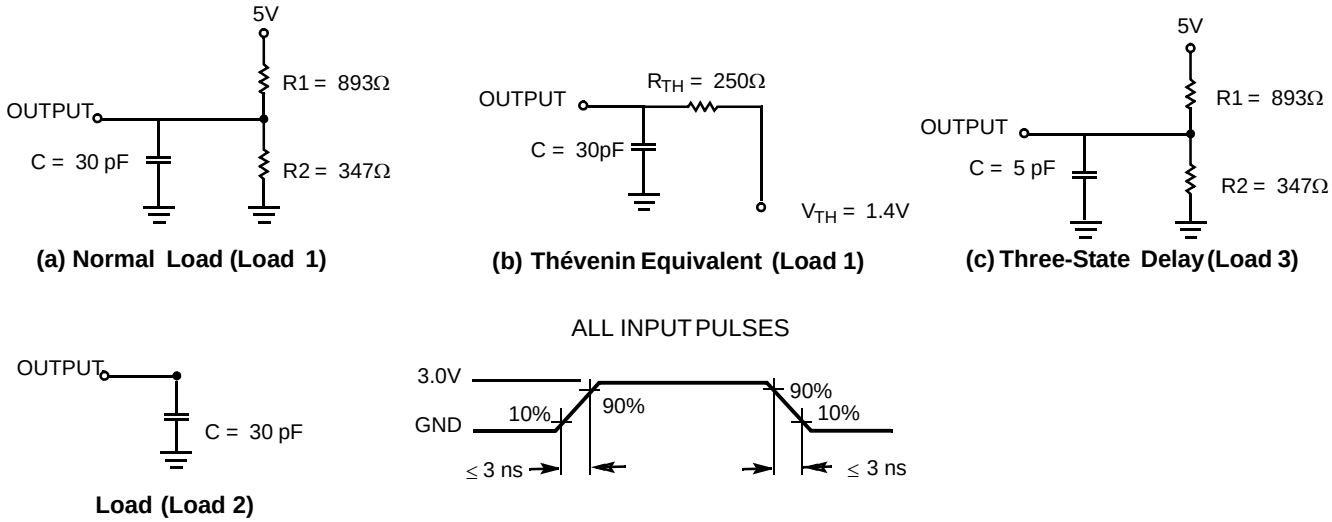
Electrical Characteristics Over the Operating Range (continued)

Parameter	Description	Test Conditions		7C024/024A/0241–35 7C025/0251–35			7C024/024A/0241–55 7C025/0251–55			Unit
				Min	Typ	Max	Min	Typ	Max	
I_{CC}	Operating Current	V_{CC} = Max, I_{OUT} = 0 mA, Outputs Disabled	Com'l		160	230		150	230	mA
			Ind		160	260		150	260	
I_{SB1}	Standby Current (Both Ports TTL Levels)	$\overline{CE}_L$ and $\overline{CE}_R \geq V_{IH}$, f = f_{MAX}[12]	Com'l		30	50		20	50	mA
			Ind		30	65		20	65	
I_{SB2}	Standby Current (One Port TTL Level)	$\overline{CE}_L$ or $\overline{CE}_R \geq V_{IH}$, f = f_{MAX}[12]	Com'l		85	135		75	135	mA
			Ind		85	150		75	150	
I_{SB3}	Standby Current (Both Ports CMOS Levels)	Both Ports $\overline{CE}$ and $\overline{CE}_R \geq$ V_{CC} – 0.2V, $V_{IN} \geq V_{CC}$ – 0.2V or $V_{IN} \leq$ 0.2V, f = 0[12]	Com'l		3	15		3	15	mA
			Ind		3	15		3	15	
I_{SB4}	Standby Current (Both Ports CMOS Levels)	One Port $\overline{CE}_L$ or $\overline{CE}_R \geq V_{CC}$ – 0.2V, $V_{IN} \geq V_{CC}$ – 0.2V or $V_{IN} \leq$ 0.2V, Active Port Outputs, f = f_{MAX}[12]	Com'l		80	120		70	120	mA
			Ind		80	135		70	135	

Capacitance[13]

Parameter	Description	Test Conditions	Max	Unit
C_{IN}	Input Capacitance	T_A = 25×C, f = 1 MHz, V_{CC} = 5.0V	10	pF
C_{OUT}	Output Capacitance		10	pF

Figure 3. AC Test Loads and Waveforms



Note
13. Tested initially and after any design or process changes that may affect these parameters.

Switching Characteristics Over the Operating Range [14]

Parameter	Description	7C024/024A/0241–15 7C025/0251–15		7C024/024A/0241–25 7C025/0251–25		7C024/024A/0241–35 7C025/0251–35		7C024/024A/0241–55 7C025/0251–55		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
Read Cycle										
t_{RC}	Read Cycle Time	15		25		35		55		ns
t_{AA}	Address to Data Valid		15		25		35		55	ns
t_{OHA}	Output Hold From Address Change	3		3		3		3		ns
t_{ACE}[15]	$\overline{CE}$ LOW to Data Valid		15		25		35		55	ns
t_{DOE}	$\overline{OE}$ LOW to Data Valid		10		13		20		25	ns
t_{LZOE}[16, 17, 18]	$\overline{OE}$ Low to Low Z	3		3		3		3		ns
t_{HZOE}[16, 17, 18]	$\overline{OE}$ HIGH to High Z		10		15		20		25	ns
t_{LZCE}[16, 17, 18]	$\overline{CE}$ LOW to Low Z	3		3		3		3		ns
t_{HZCE}[16, 17, 18]	$\overline{CE}$ HIGH to High Z		10		15		20		25	ns
t_{PU}[18]	$\overline{CE}$ LOW to Power Up	0		0		0		0		ns
t_{PD}[18]	$\overline{CE}$ HIGH to Power Down		15		25		25		55	ns
t_{ABE}[15]	Byte Enable Access Time		15		25		35		55	ns
Write Cycle										
t_{WC}	Write Cycle Time	15		25		35		55		ns
t_{SCE}[15]	$\overline{CE}$ LOW to Write End	12		20		30		35		ns
t_{AW}	Address Setup to Write End	12		20		30		35		ns
t_{HA}	Address Hold From Write End	0		0		0		0		ns
t_{SA}[15]	Address Setup to Write Start	0		0		0		0		ns
t_{PWE}	Write Pulse Width	12		20		25		35		ns
t_{SD}	Data Setup to Write End	10		15		15		20		ns
t_{HD}	Data Hold From Write End	0		0		0		0		ns
t_{HZWE}[17, 18]	R/$\overline{W}$ LOW to High Z		10		15		20		25	ns
t_{LZWE}[17, 18]	R/$\overline{W}$ HIGH to Low Z	0		0		0		0		ns
t_{WDD}[19]	Write Pulse to Data Delay		30		50		60		70	ns
t_{DDD}[19]	Write Data Valid to Read Data Valid		25		35		35		45	ns

Notes
14. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, and output loading of the specified I_{OL}/I_{OH} and 30 pF load capacitance.
15. To access RAM, $\overline{CE}$=L, $\overline{UB}$=L, $\overline{SEM}$=H. To access semaphore, $\overline{CE}$=H and $\overline{SEM}$=L. Either condition must be valid for the entire t_{SCE} time.
16. At any given temperature and voltage condition for any given device, t_{HZCE} is less than t_{LZCE} and t_{HZOE} is less than t_{LZOE}.
17. Test conditions used are Load 3.
18. This parameter is guaranteed but not tested.
19. For information on port-to-port delay through RAM cells from writing port to reading port, refer to Figure 11.

Switching Characteristics Over the Operating Range (continued)[14]

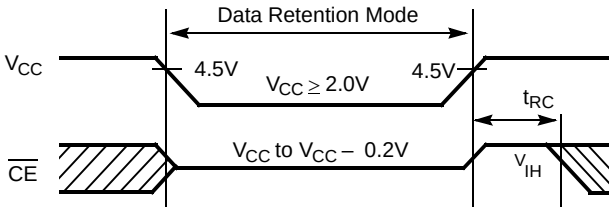
Parameter	Description	7C024/024A/0241–15 7C025/0251–15		7C024/024A/0241–25 7C025/0251–25		7C024/024A/0241–35 7C025/0251–35		7C024/024A/0241–55 7C025/0251–55		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
Busy Timing[20]										
t_{BLA}	BUSY LOW from Address Match		15		20		20		45	ns
t_{BHA}	BUSY HIGH from Address Mismatch		15		20		20		40	ns
t_{BLC}	BUSY LOW from CE LOW		15		20		20		40	ns
t_{BHC}	BUSY HIGH from CE HIGH		15		20		20		35	ns
t_{PS}	Port Setup for Priority	5		5		5		5		ns
t_{WB}	R/W HIGH after BUSY (Slave)	0		0		0		0		ns
t_{WH}	R/W HIGH after BUSY HIGH (Slave)	13		20		30		40		ns
t_{BDD}[21]	BUSY HIGH to Data Valid		Note 21		Note 21		Note 21		Note 21	ns
Interrupt Timing[20]										
t_{INS}	INT Set Time		15		20		25		30	ns
t_{INR}	INT Reset Time		15		20		25		30	ns
Semaphore Timing										
t_{SOP}	SEM Flag Update Pulse (OE or SEM)	10		12		15		20		ns
t_{SWRD}	SEM Flag Write to Read Time	5		10		10		15		ns
t_{SPS}	SEM Flag Contention Window	5		10		10		15		ns
t_{SAA}	SEM Address Access Time		15		25		35		55	ns

Data Retention Mode

The CY7C024/024A/0241 is designed with battery backup in mind. Data retention voltage and supply current are guaranteed over temperature. The following rules insure data retention:

1. Chip enable (CE) must be held HIGH during data retention, within V_{CC} to V_{CC} – 0.2V.
2. CE must be kept between V_{CC} – 0.2V and 70% of V_{CC} during the power up and power down transitions.
3. The RAM can begin operation >t_{RC} after V_{CC} reaches the minimum operating voltage (4.5V).

Timing



Parameter	Test Conditions[22]	Max	Unit
ICC_{DR1}	At VCC_{DR} = 2V	1.5	mA

Notes

20. Test conditions used are Load 2.
21. t_{BDD} is a calculated parameter and is the greater of t_{WDD}– t_{PWE} (actual) or t_{DDD}– t_{SD} (actual).
22. CE = V_{CC}, V_{in} = GND to V_{CC}, T_A = 25°C. This parameter is guaranteed but not tested.

Switching Waveforms

Figure 4. Read Cycle No. 1 (Either Port Address Access)[23, 24, 25]

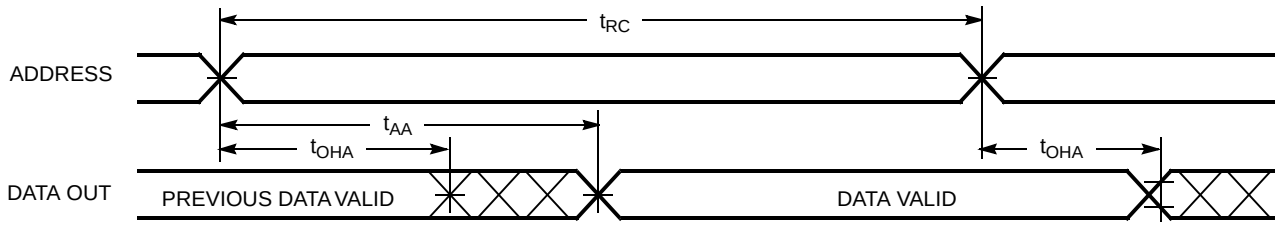


Figure 5. Read Cycle No. 2 (Either Port $\overline{CE}$/$\overline{OE}$ Access)[23, 26, 27]

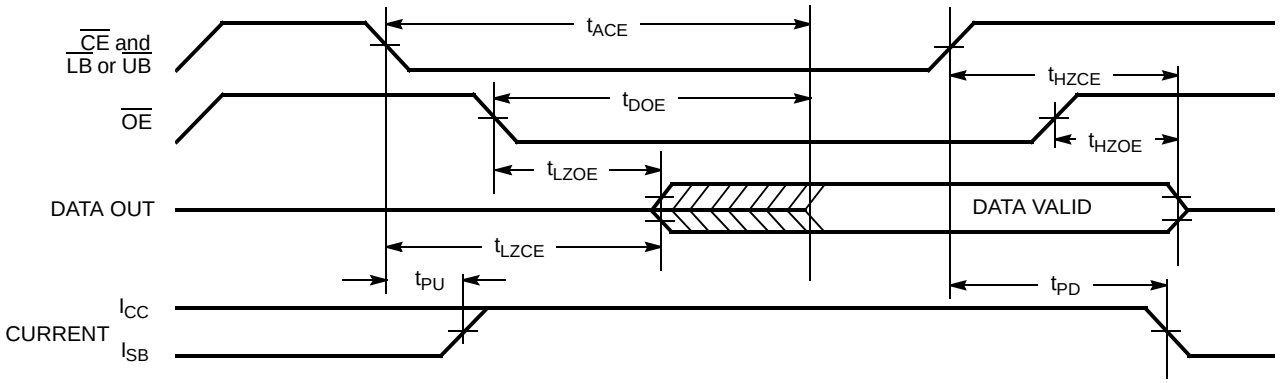
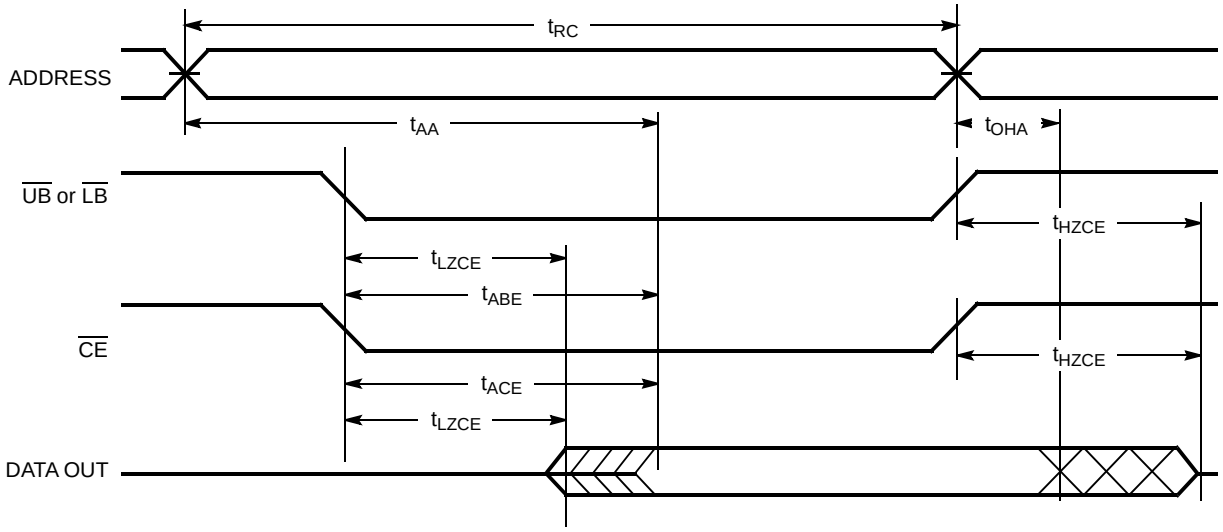


Figure 6. Read Cycle No. 3 (Either Port)[23, 25, 26, 26, 27]



Notes
23. R/$\overline{W}$ is HIGH for read cycles
24. Device is continuously selected $\overline{CE}$ = V_{IL} and $\overline{UB}$ or $\overline{LB}$ = V_{IL}. This waveform cannot be used for semaphore reads.
25. $\overline{OE}$ = V_{IL}.
26. Address valid prior to or coincident with $\overline{CE}$ transition LOW.
27. To access RAM, $\overline{CE}$ = V_{IL}, $\overline{UB}$ or $\overline{LB}$ = V_{IL}, $\overline{SEM}$ = V_{IH}. To access semaphore, $\overline{CE}$ = V_{IH}, $\overline{SEM}$ = V_{IL}.

Switching Waveforms (continued)

Figure 7. Write Cycle No. 1: R/$\overline{W}$ Controlled Timing[28, 29, 30, 31]

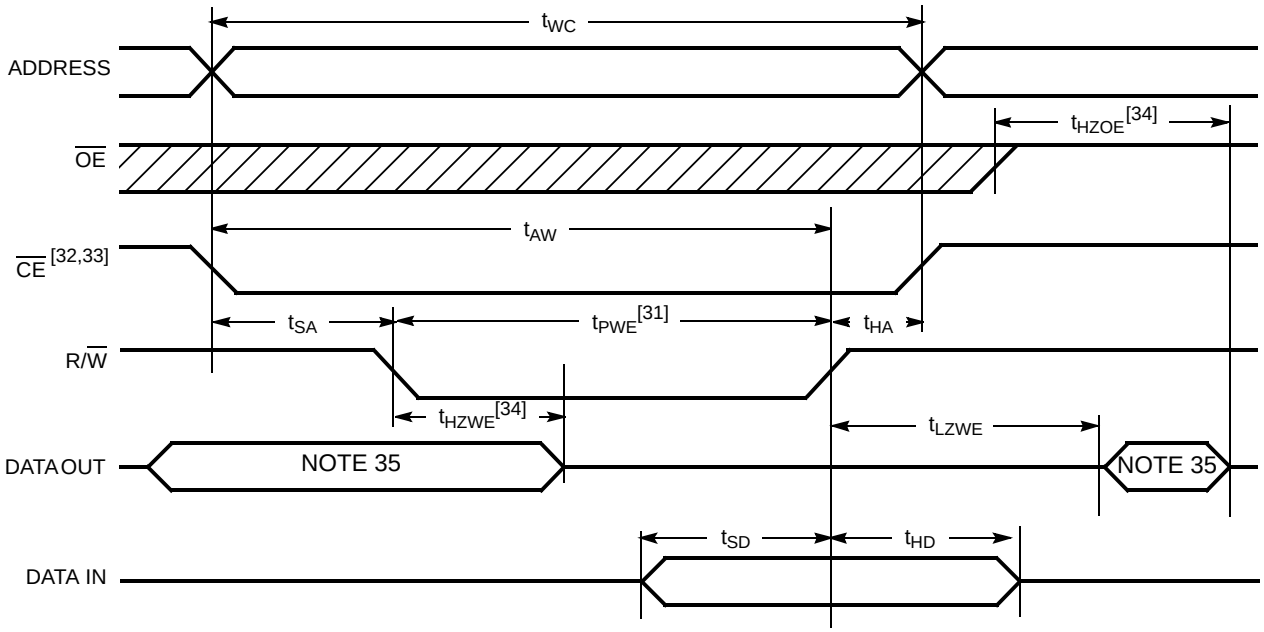
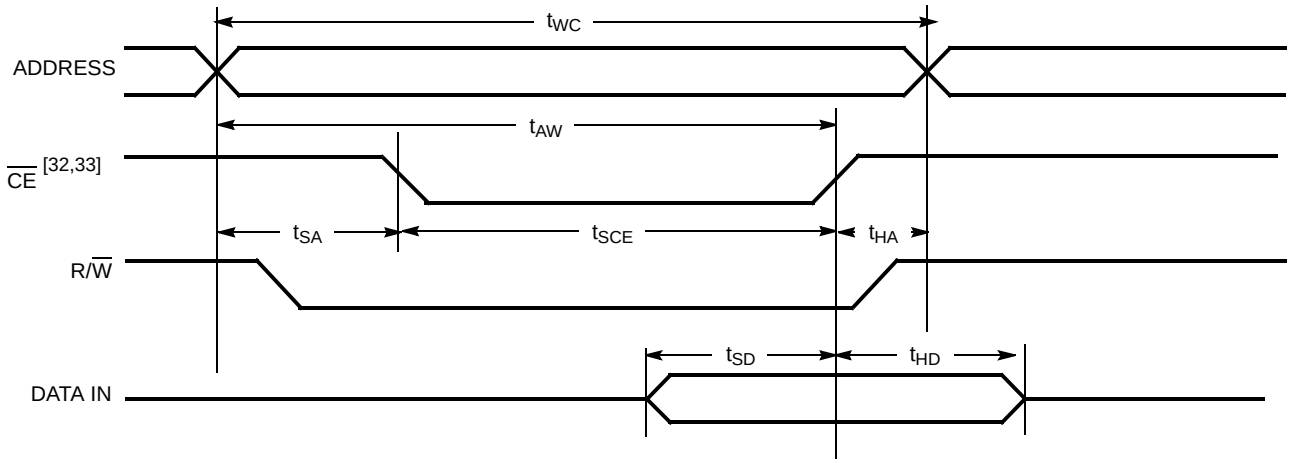


Figure 8. Write Cycle No. 2: $\overline{CE}$ Controlled Timing[28, 29, 30, 36]



Notes
28. R/$\overline{W}$ must be HIGH during all address transitions.
29. A write occurs during the overlap (t_{SCE} or t_{PWE}) of a LOW $\overline{CE}$ or $\overline{SEM}$ and a LOW $\overline{UB}$ or $\overline{LB}$.
30. t_{HA} is measured from the earlier of $\overline{CE}$ or R/$\overline{W}$ or ($\overline{SEM}$ or R/$\overline{W}$) going HIGH at the end of write cycle.
31. If $\overline{OE}$ is LOW during a R/$\overline{W}$ controlled write cycle, the write pulse width must be the larger of t_{PWE} or ($t_{HZWE} + t_{SD}$) to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{SD}. If $\overline{OE}$ is HIGH during an R/$\overline{W}$ controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified t_{PWE}.
32. To access RAM, $\overline{CE}$ = V_{IL}, $\overline{SEM}$ = V_{IH}.
33. To access upper byte, $\overline{CE}$ = V_{IL}, $\overline{UB}$ = V_{IL}, $\overline{SEM}$ = V_{IH}.
To access lower byte, $\overline{CE}$ = V_{IL}, $\overline{LB}$ = V_{IL}, $\overline{SEM}$ = V_{IH}.
34. Transition is measured ±500 mV from steady state with a 5 pF load (including scope and jig). This parameter is sampled and not 100% tested.
35. During this period, the I/O pins are in the output state, and input signals must not be applied.
36. If the $\overline{CE}$ or $\overline{SEM}$ LOW transition occurs simultaneously with or after the R/$\overline{W}$ LOW transition, the outputs remain in the high impedance state.

Switching Waveforms (continued)

Figure 9. Semaphore Read After Write Timing, Either Side[37]

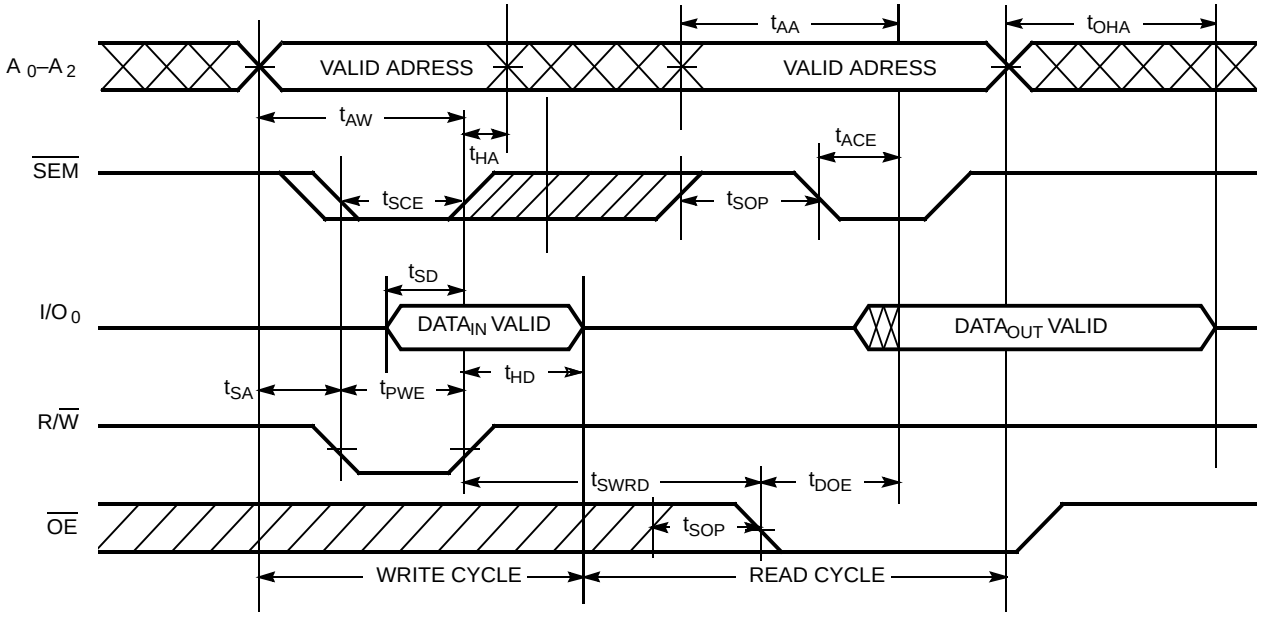
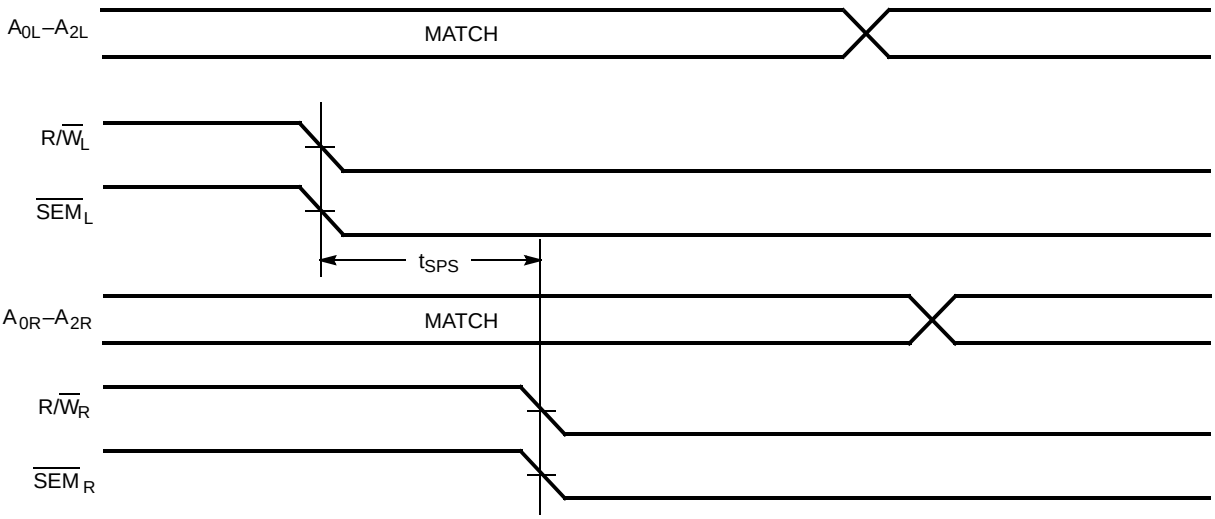


Figure 10. Timing Diagram of Semaphore Contention[38, 39, 40]



Notes
37. CE = HIGH for the duration of the above timing (both write and read cycle).
38. $I/O_{0R} = I/O_{0L}$ = LOW (request semaphore); $\overline{CE}_R = \overline{CE}_L$ = HIGH.
39. Semaphores are reset (available to both ports) at cycle start.
40. If t_{SPS} is violated, the semaphore is definitely obtained by one side or the other, but which side gets the semaphore is unpredictable.

Switching Waveforms (continued)

Figure 11. Timing Diagram of Read with $\overline{BUSY}$ (M/$\overline{S}$=HIGH)[41]

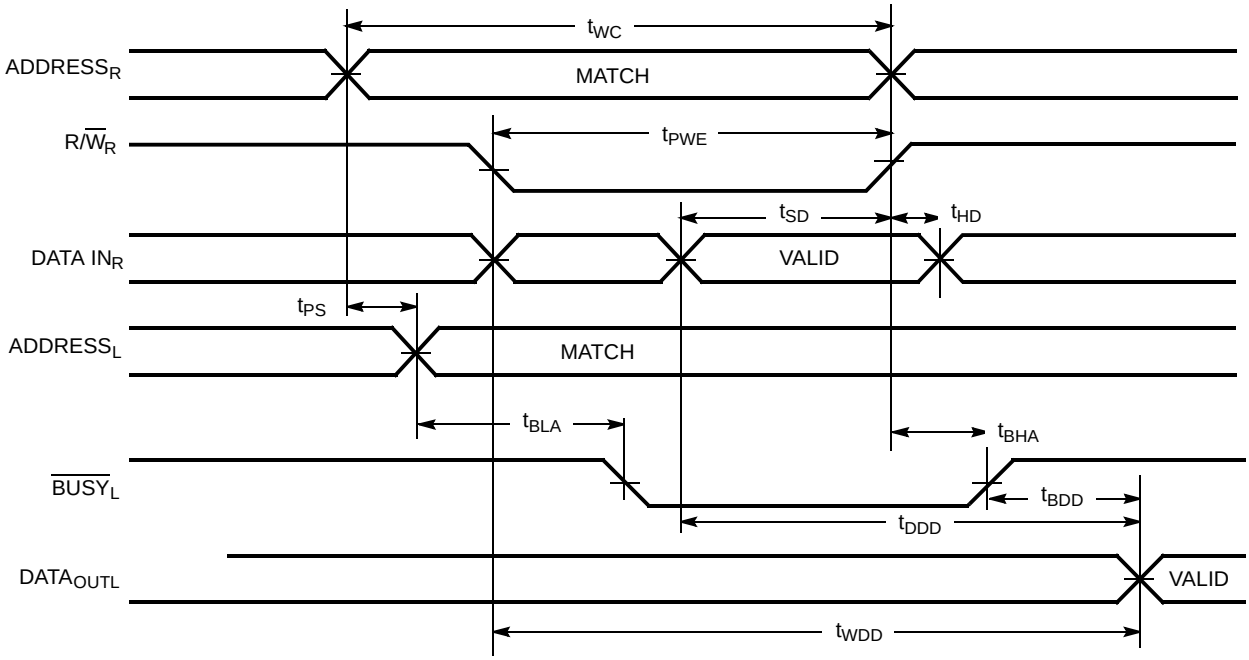
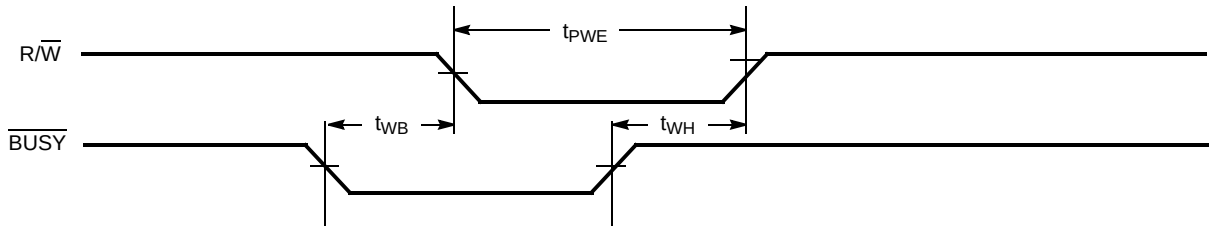


Figure 12. Write Timing with Busy Input (M/$\overline{S}$=LOW)

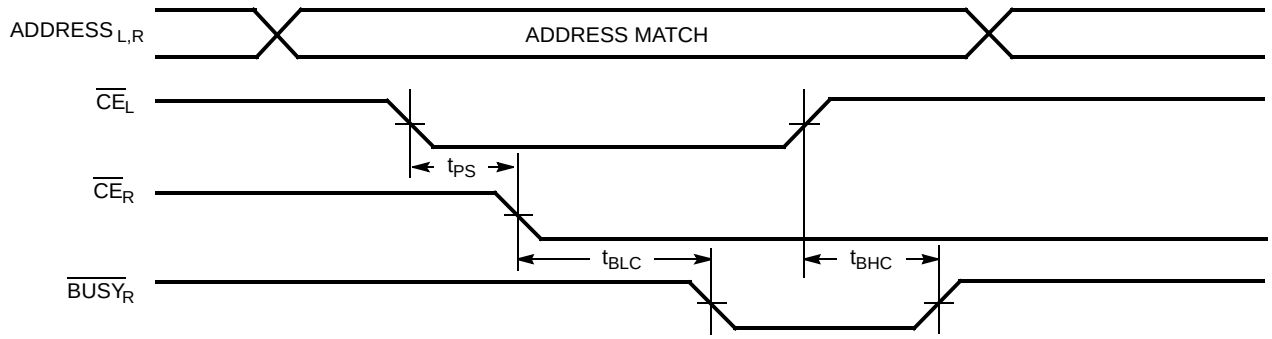


Note
41. $\overline{CE}_L$ = $\overline{CE}_R$ = LOW

Switching Waveforms (continued)

Figure 13. Busy Timing Diagram No.1 (CE Arbitration)[42]

$\overline{CE}_L$ Valid First:



CE_R Valid First:

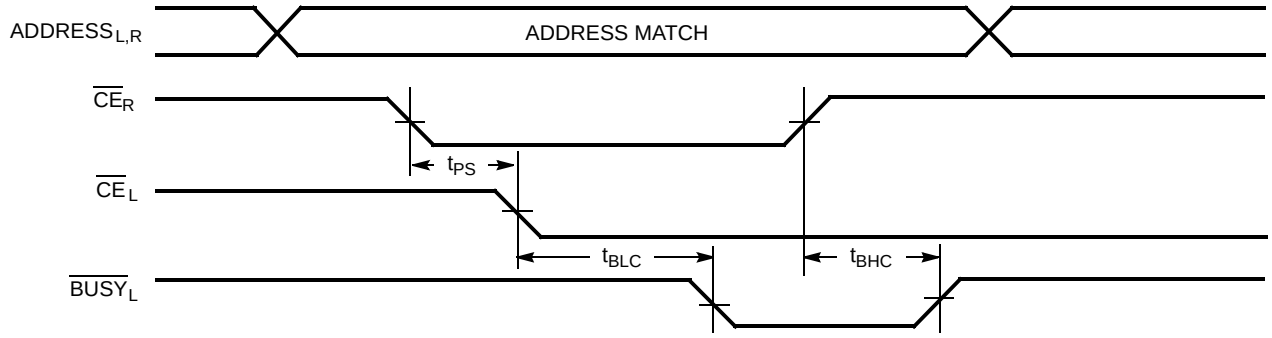
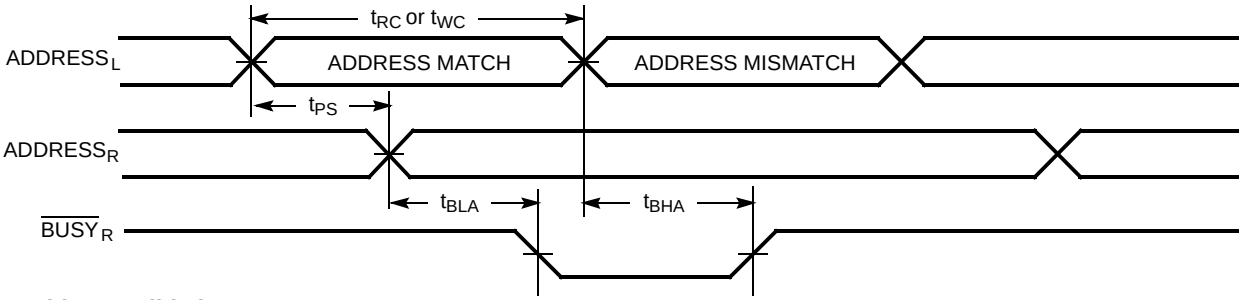
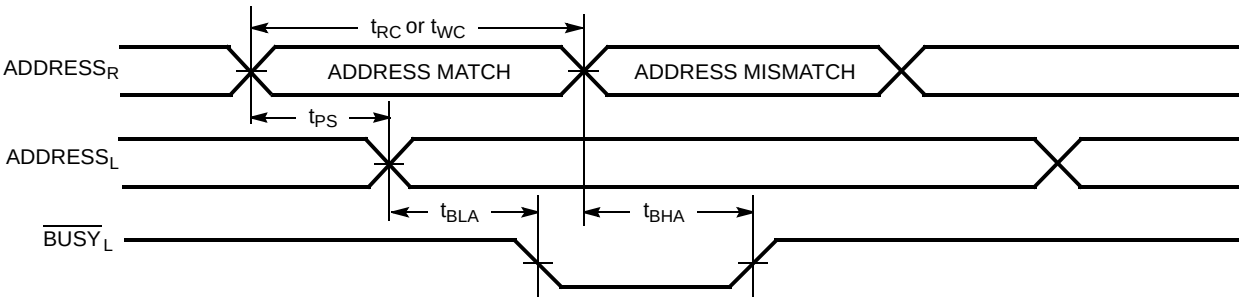


Figure 14. Busy Timing Diagram No.2 (Address Arbitration)[42]

Left Address Valid First:



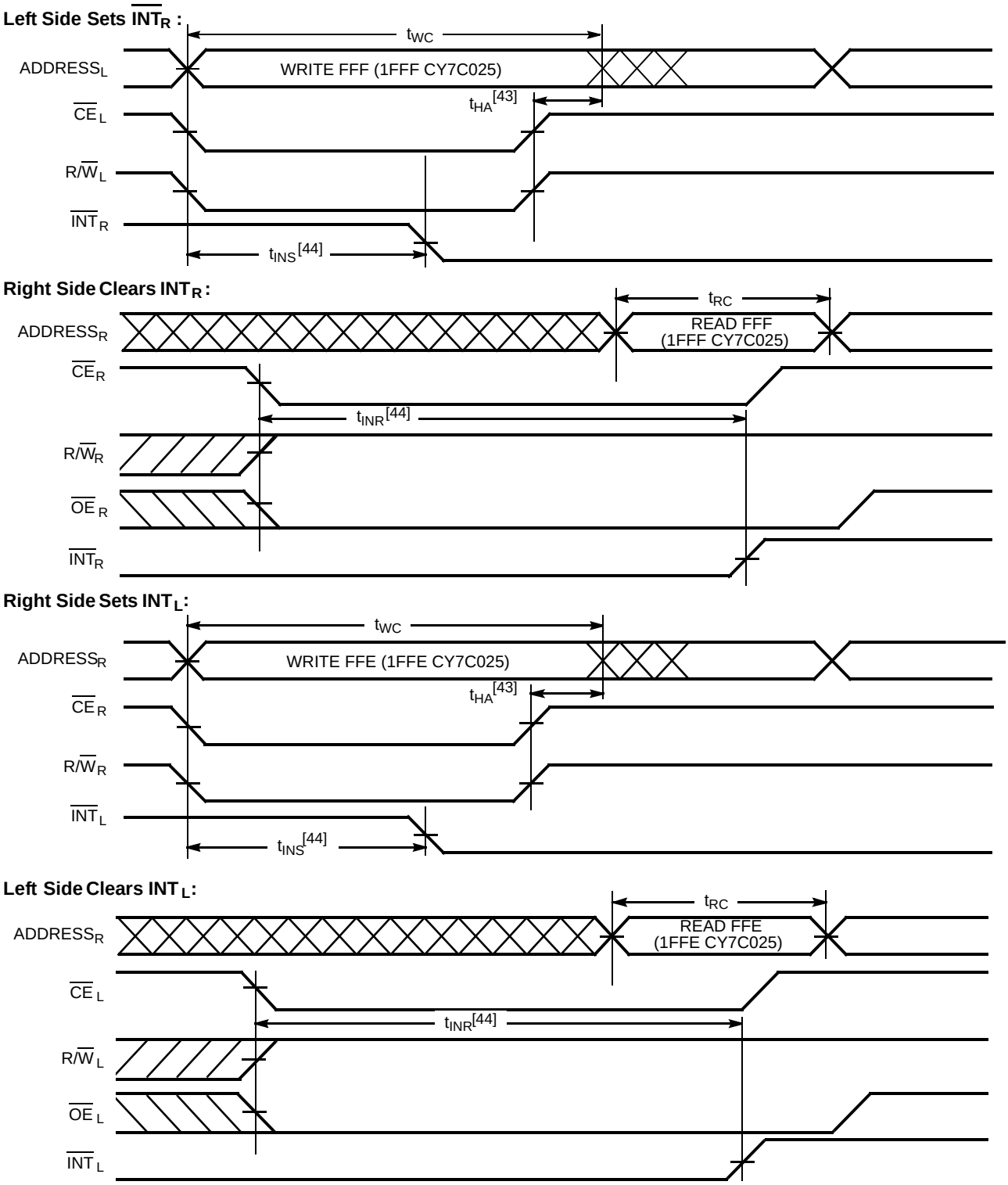
Right Address Valid First:



Note
42. If t_{PS} is violated, the busy signal is asserted on one side or the other, but there is no guarantee to which side $\overline{BUSY}$ is asserted.

Switching Waveforms (continued)

Figure 15. Interrupt Timing Diagrams



Notes
43. t_{HA} depends on which enable pin ($\overline{CE}_L$ or $R/\overline{W}_L$) is deasserted first.
44. t_{INS} or t_{INR} depends on which enable pin ($\overline{CE}_L$ or $R/\overline{W}_L$) is asserted last.

Ordering Information (4K x16 Dual-Port SRAM)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
15	CY7C024–15AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C024-15AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C024–15JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C024-15JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
25	CY7C024–25AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C024-25AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C024–25JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C024A-25JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
	CY7C024–25AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C024-25AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C024–25JI	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C024-25JXI	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
35	CY7C024–35AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C024-35AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C024–35JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C024-35JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
	CY7C024–35AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C024-35AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C024–35JI	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C024-35JXI	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
55	CY7C024–55AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C024-55AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C024–55JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C024-55JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
	CY7C024–55AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C024-55AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C024–55JI	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C024-55JXI	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	

Ordering Information (8K x 16 Dual-Port SRAM)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
15	CY7C025–15AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C025-15AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C025–15JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C025-15JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
	CY7C025–15AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C025-15AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	

Ordering Information (8K x 16 Dual-Port SRAM) (continued)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
25	CY7C025–25AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C025-25AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C025–25JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C025-25JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
	CY7C025–25AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C025-25AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C025–25JI	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C025-25JXI	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
35	CY7C025–35AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C025-35AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C025–35JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C025-35JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
	CY7C025–35AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C025-35AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C025–35JI	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C025-35JXI	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
55	CY7C025–55AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C025-55AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C025–55JC	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C025-55JXC	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	
	CY7C025–55AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C025-55AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C025–55JI	J83	84-Pin Plastic Leaded Chip Carrier	
	CY7C025-55JXI	J83	84-Pin Pb Free Plastic Leaded Chip Carrier	

Ordering Information (4K x 18 Dual-Port SRAM)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
15	CY7C0241–15AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0241-15AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C0241–15AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C0241-15AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
25	CY7C0241–25AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0241-25AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C0241–25AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C0241-25AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
35	CY7C0241–35AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0241-35AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C0241–35AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C0241-35AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	

Ordering Information (4K x 18 Dual-Port SRAM) (continued)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
55	CY7C0241–55AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0241-55AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C0241–55AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C0241-55AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	

8K x 18 Dual-Port SRAM

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
15	CY7C0251–15AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0251–15AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
25	CY7C0251–25AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0251-25AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C0251–25AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C0251–25AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
35	CY7C0251–35AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0251–35AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C0251–35AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C0251–35AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	
55	CY7C0251–55AC	A100	100-Pin Thin Quad Flat Pack	Commercial
	CY7C0251–55AXC	A100	100-Pin Pb Free Thin Quad Flat Pack	
	CY7C0251–55AI	A100	100-Pin Thin Quad Flat Pack	Industrial
	CY7C0251–55AXI	A100	100-Pin Pb Free Thin Quad Flat Pack	

Package Diagrams

Figure 16. 100-Pin Pb-Free Thin Plastic Quad Flat Pack (TQFP) A100

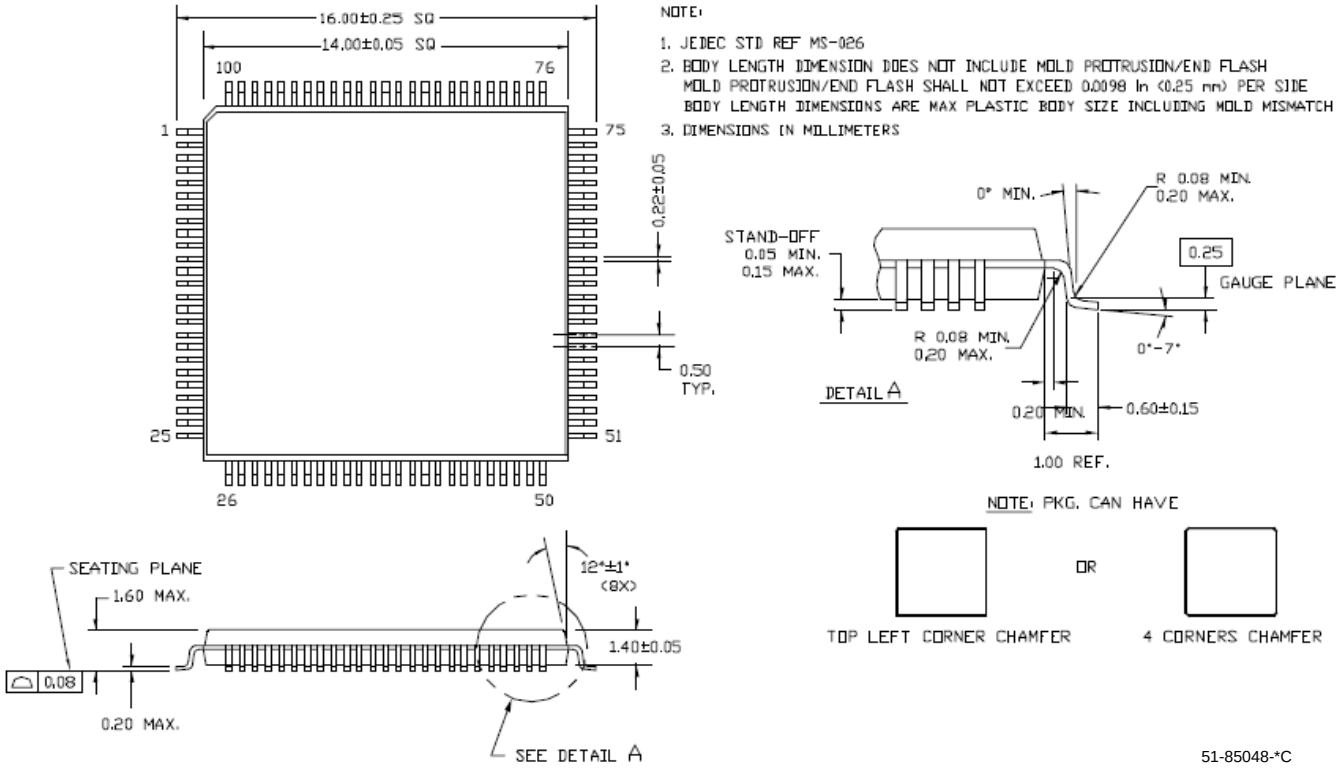
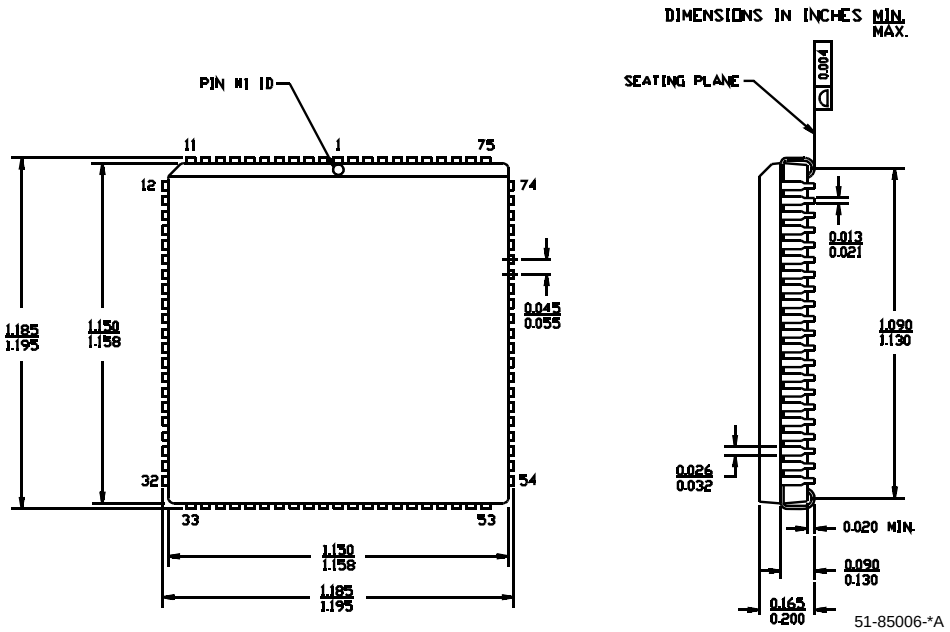


Figure 17. 84-Pin Pb Free Plastic Leaded Chip Carrier J83



Document History Page

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Rev.	**ECN No.**	**Orig. of Change**	**Submission Date**	**Description of Change**
**	110177	SZV	09/29/01	Change from Spec number: 38-00255 to 38-06035
*A	122286	RBI	12/27/02	Power up requirements added to Maximum Ratings Information
*B	236754	YDT	See ECN	Removed cross information from features section
*C	279132	RUY	See ECN	Added Lead (Pb)-Free packaging information
*D	2623540	VKN/PYRS	12/17/08	Added CY7C024A part Updated Ordering information table

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